

# 200GbE to 4x53GbE (QSFP56 to 4xSFP56) MMF Active Optical Splitter Cable P/N: GQP-MDO201-XXXC

## Features

- ✓ 4 channels full-duplex transceiver modules
- ✓ Transmission data rate up to 53Gbps per channel
- ✓ Low power dissipation <5W (200G End)
- ✓ Low power dissipation <2W (50G End)</p>
- ✓ RoHS-6 compliant (lead-free)
- ✓ Commercial case temperature range of 0°C to 70°C
- ✓ Single 3.3V power supply
- ✓ Maximum link length of 70m onOM3 MMF and100m on OM4& OM5 MMF
- ✓ Uncooled 850nmVCSEL array (both End)
- ✓ PIN photo detector array (both End)
- ✓ 200GBASE-SR4 and 50GBASE-SR compliant
- ✓ I2C management interface
- ✓ CMIS V4.0 compliant

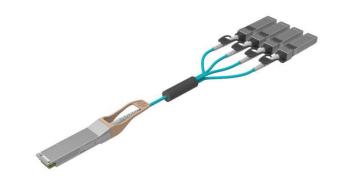
### Applications

- ✓ IEEE 802.3cd 200GBASE-SR4 Ethernet (PAM4)
- ✓ IEEE 802.3cd 50GBASE-SR Ethernet

### Description

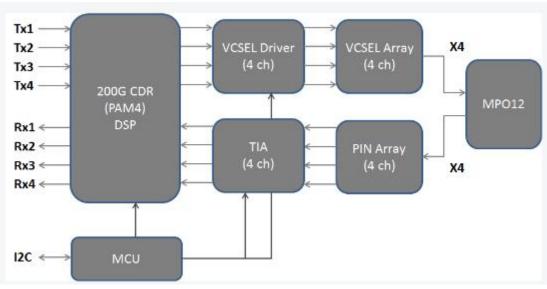
Gigalight's GQP-MDO201-XXXC MMF Active Optical Splitter Cable is used in 4 X 50 Gigabit Ethernet links over OM3/OM4/OM5 multimode fiber, which provides connectivity between system units with a 200GbE connector on one side and four separate 50GbEconnectors on the other four sides. The cable connects data signals from each of the 4 MMF (Multi Mode Fiber) pairs on the single QSFP56 end to the four pair of each of the SFP56 multiport ends.

Gigalight's GQP-MDO201-XXXC MMF Active Optical Splitter Cable is compliant with the QSFP-MSA and with 50GBASE-SRspecification. Digital diagnostics functions are available via the I2C interface as specified by CMIS V4.0. The transceiver is RoHS 2.0 compliant and lead-free per Directive 2011/65/EU.





### QSFP56 End



### SFP56 end

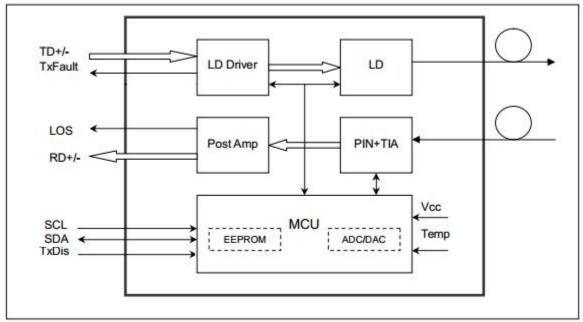


Figure 1. Module Block Diagram

### **Absolute Maximum Ratings**

Parameter	Symbol	Min	Мах	Unit
Supply Voltage	V <sub>cc</sub>	-0.3	3.6	V
Input Voltage	Vin	-0.3	V <sub>cc</sub> +0.3	V
Storage Temperature	Ts	-20	85	°C
Case Operating Temperature	Tc	0	70	°C
Humidity (non-condensing)	Rh	5	95	%



## **Recommended Operating Conditions**

Parameter	Symbol	Min	Typical	Max	Unit
Supply Voltage	V <sub>cc</sub>	3.13	3.3	3.47	V
Operating Case Temperature	Tc	0		70	°C
Baud Rate per Lane (PAM4)	fd		26.5625		GBaud/s
Humidity	Rh	5		85	%
Power Dissipation	Pm			5.0/2.0	W
Fiber Bend Radius	Rb	3			cm

### **Electrical Specifications**

Parameter	Symbol	Min	Typical	Max	Unit
Differential Input Impedance	Zin	90	100	110	ohm
Differential Output Impedance	Zout	90	100	110	ohm
Differential Input Voltage Amplitude	ΔV <sub>in</sub>	300		900	mVppd
Differential Output Voltage Amplitude	ΔV <sub>out</sub>	300		900	mVppd
Bit Error Rate Note2	BER			2.4E-4	

#### Note:

Note2. Pre-FEC BER, compliant with 200GBASE-SR4 specification.

### **Optical Characteristics(QSFP56 end)**

Parameter	Symbol	Min	Typical	Max	Unit				
Trar	Transmitter								
Center Wavelength	λc	840	850	860	nm				
RMS Spectral Width	Δλ			0.6	nm				
Average Launch Power (each lane)	Pout	-6		4	dBm				
Outer Optical Modulation Amplitude (each lane)	OMA <sub>out</sub>	-4		3	dBm				
Launch power in OMA <sub>outer</sub> minus TDECQ	Ptdecq	-5.9			dBm				
Transmitter and dispersion eye closure (each lane)	TDECQ			4.9	dB				
Average launch power of off transmitter(each lane)	Poff			-30	dBm				
Outer Extinction Ratio	ER	3			dB				
Optical Return Loss Tolerance	ORLT			12	dB				
Re	ceiver								
Center Wavelength	λ <sub>c</sub>	840	850	860	nm				
Damage threshold	Rdam	6			dBm				
Average Receive Power (each lane)	Pin	-7.9		4	dBm				
Receiver Power (OMA <sub>outer</sub> ) (each lane)	OMA <sub>out</sub>			3	dBm				
Receiver reflectance	Pref			-12	dB				
Stressed Sensitivity (OMA <sub>outer</sub> ) (each lane) Note3	Sens			-3	dBm				
Receiver Sensitivity (OMA <sub>outer</sub> ) (each lane) Note3	Seno			-7	dB				

### Note:

Note3. Measured with conformance test signal at TP3 for the BER specified in IEEE 802.3cd.



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## **Optical Characteristics(SFP56 end)**

Parameter	Symbol	Min	Typical	Max	Unit	Notes
		Transmit	ter			- -
Centre Wavelength	λс	840	850	860	nm	-
RMS spectral width	Δλ	-	-	0.6	nm	-
Average launch power, each lane	Pout	-6	-	4	dBm	-
Optical Modulation Amplitude (OMAouter), each lane	OMA	-4		3	dBm	-
Transmitter and dispersion eye closure(TDEC)	TDEC			4.9	dB	
Extinction Ratio	ER	3	-	-	dB	-
Average launch power of OFF transmitter				-30	dB	-
		Receive	er		_	_
Centre Wavelength	λς	840	850	860	nm	-
Receiver Sensitivity in OMAout	RXsen			-6.5	dBm	Note3
Stressed Receiver Sensitivity in OMAout				-3.4	dBm	Note3
Maximum Average power at receiver , each lane input, each lane				4	dBm	-
Minimum Average power at receiver , each lane		-7.9			dBm	
Receiver Reflectance				-12	dB	-
LOS Assert		-10.5			dBm	-
LOS De-Assert – OMA				-10	dBm	-
LOS Hysteresis		0.5			dB	-

### Note:

Note3. Measured with conformance test signal at TP3 for the BER specified in IEEE 802.3cd.

## Pin Description(QSFP56 end)

Pin	Logic	Symbol	Name/Description
1		GND	Module Ground <sup>Note6</sup>
2	CML-I	Tx2-	Transmitter inverted data input
3	CML-I	Tx2+	Transmitter non-inverted data input
4		GND	Module Ground Note6
5	CML-I	Tx4-	Transmitter inverted data input
6	CML-I	Tx4+	Transmitter non-inverted data input
7		GND	Module Ground <sup>Note6</sup>



#### 深圳市易飞扬通信技术有限公司 Shenzhen Gigalight Technology Co., Ltd.

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-			ht i i o i chiete7
8	LVTTL-I	MODSEIL	Module Select <sup>Note7</sup>
9	LVTTL-I	ResetL	Module Reset <sup>Note7</sup>
10		VCCRx	+3.3V Receiver Power Supply
11	LVCMOS-I	SCL	2-wire Serial interface clock <sup>Note7</sup>
12	LVCMOS-I/O	SDA	2-wire Serial interface data <sup>Note7</sup>
13		GND	Module Ground <sup>Note6</sup>
14	CML-O	RX3+	Receiver non-inverted data output
15	CML-O	RX3-	Receiver inverted data output
16		GND	Module Ground <sup>Note6</sup>
17	CML-O	RX1+	Receiver non-inverted data output
18	CML-O	RX1-	Receiver inverted data output
19		GND	Module Ground <sup>Note6</sup>
20		GND	Module Ground <sup>Note6</sup>
21	CML-O	RX2-	Receiver inverted data output
22	CML-O	RX2+	Receiver non-inverted data output
23		GND	Module Ground <sup>Note6</sup>
24	CML-O	RX4-	Receiver inverted data output
25	CML-O	RX4+	Receiver non-inverted data output
26		GND	Module Ground <sup>Note6</sup>
27	LVTTL-O	ModPrsL	Module Present, internal pulled down to GND
28	LVTTL-O	IntL	Interrupt output, should be pulled up on host board <sup>2</sup>
29		VCCTx	+3.3V Transmitter Power Supply
30		VCC1	+3.3V Power Supply
31	LVTTL-I	LPMode	Low Power Mode <sup>Note7</sup>
32		GND	Module Ground <sup>Note6</sup>
33	CML-I	Tx3+	Transmitter non-inverted data input
34	CML-I	Tx3-	Transmitter inverted data input
35		GND	Module Ground <sup>Note6</sup>
36	CML-I	Tx1+	Transmitter non-inverted data input
37	CML-I	Tx1-	Transmitter inverted data input
38		GND	Module Ground <sup>Note6</sup>

### Note:

Note4. Module circuit ground is isolated from module chassis ground within the module. Note5. Open collector should be pulled up with 4.7K to 10K ohms on host board to a voltage between 3.15V and 3.6V.



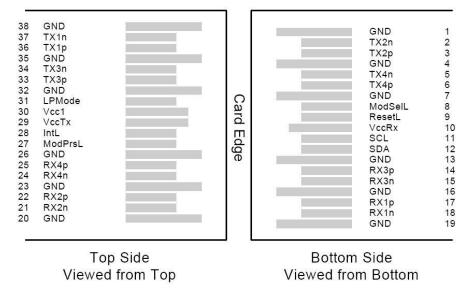


Figure 2. Electrical Pin-out Details

### ModSelL Pin

The ModSelL is an input pin. When held low by the host, the module responds to 2-wire serial communication commands. The ModSelL allows the use of multiple QSFP modules on a single 2-wire interface bus. When the ModSelL is "High", the module will not respond to any 2-wire interface communication from the host. ModSelL has an internal pull-up in the module.

#### **ResetL Pin**

Reset. LPMode\_Reset has an internal pull-up in the module. A low level on the ResetL pin for longer than the minimum pulse length (t\_Reset\_init) initiates a complete module reset, returning all user module settings to their default state. Module Reset Assert Time (t\_init) starts on the rising edge after the low level on the ResetL pin is released. During the execution of a reset (t\_init) the host shall disregard all status bits until the module indicates a completion of the reset interrupt. The module indicates this by posting an IntL signal with the Data\_Not\_Ready bit negated. Note that on power up (including hot insertion) the module will post this completion of reset interrupt without requiring a reset.

#### LPMode Pin

Gigalight QSFP28 modules operate in the low power mode (less than 1.5 W power consumption). This pin active high will decrease power consumption to less than 1W.

#### ModPrsL Pin

ModPrsL is pulled up to Vcc on the host board and grounded in the module. The ModPrsL is asserted "Low" when the module is inserted and deasserted "High" when the module is physically absent from the host connector.

#### IntL Pin

IntL is an output pin. When "Low", it indicates a possible module operational fault or a status critical to the host system. The host identifies the source of the interrupt by using the 2-wire serial interface. The IntL pin is an open collector output and must be pulled up to Vcc on the host board.

#### **Power Supply Filtering**

The host board should use the power supply filtering shown in Figure 3.



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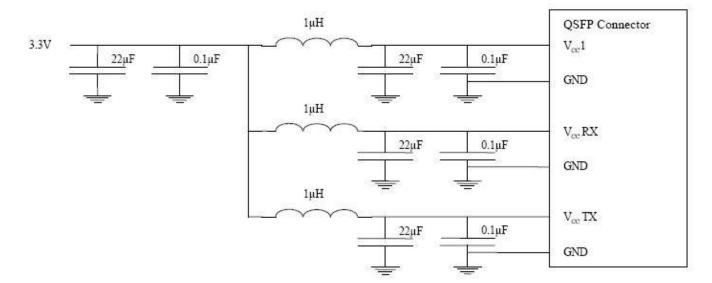


Figure 3. Host Board Power Supply Filtering

## DIAGNOSTIC MONITORING INTERFACE

Digitaldiagnostics functions are available via the I2C interface as specified by CMIS V4.0. The CMIS management memory isshown in Figure 4.

Due to eight-bit addresses, the management memory is divided in **Lower Memory** (addresses 00hthrough 7Fh) and Upper Memory (addresses 80h ~ FFh).

The addressing structure of the additional internal management memory is shown in Figure 5. Themanagement memory is arranged as a unique and always host accessible address space of 128bytes (Lower Memory) and as multiple upper address subspaces of 128 bytes each (Pages), only one of which isselected as host visible in Upper Memory. A second level of Page selection is possible for Pages for which severalinstances exist (e.g. where a **bank** of pages with the same Page number exists).

This structure supports a flat 256 byte memory for passive copper modules and permits timely access toaddresses in the Lower Memory( e.g. Flags and Monitors). Less time critical entries, e.g. serial ID information andthreshold settings, are available with the Page Select function in the Lower Page.



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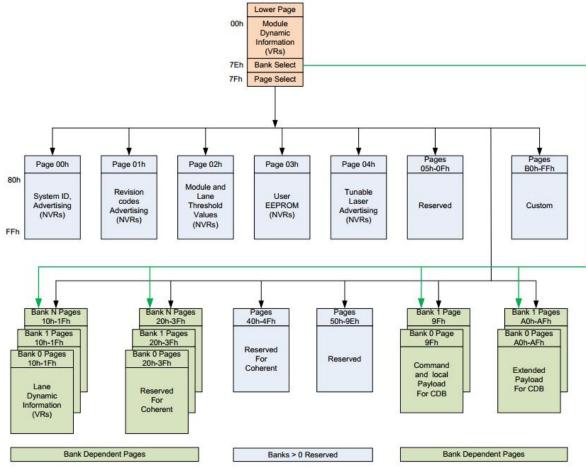
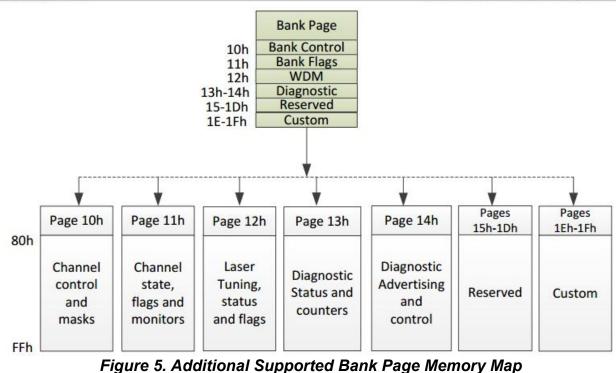


Figure 4. CMIS Bank Page Memory Map

The CMIS memory structure also provides address expansion by adding additional upper pages as needed. Upper pages 00-02 all contain static, non-volatile advertising registers. Upper page 01 provides revision codes and advertising registers that indicate the capabilities of the module. Upper page 02 provides thresholds for monitored functions. Upper page 03 provides a user read/write space.

The lower page, upper pages 00h-03h and bank 0 page 10h-11h aresupported in our module.





#### The Lower Memory – Page 00h

The Lower Memory consists of the lower 128 bytes of the 256 byte two-wire serial bus addressable space. The Lower Page is used to access a variety of module level measurements, diagnostic functions and controlfunctions, as well as to select which of the various Upper Pages in the structured memory map are accessed bybyte addresses greater or equal than 128.

Address	Size	Subject Area	Description
0–3	4	ID and Status Area	Module ID from SFF-8024 list, version number, Type and status
			Flat mem indication, CLEI present indicator, Maximum TWI speed, Current state of Module, Current state of the Interrupt signal
4-7	4	Lane Flag Summary	Flag summary of all lane flags on pages 10h-1Fh
8-13	6	Module-Level Flags	All flags that are not lane or data path specific
14-25	12	Module-Level Monitors	Monitors that are not lane or data path specific
26-30	5	Module Global Controls	Controls applicable to the module as a whole
31-36	6	Module-Level Flag Masks	Masking bits for the Module-Level flags
37-38	2	CDB Status Area	Status of most recent CDB command
39-40	2	Module Firmware Version	Module Firmware Version.
41-63	23	Reserved Area	Reserved for future standardization
64-82	19	Custom Area	Vendor or module type specific use
83-84	2	Inactive Firmware Version	Version Number of Inactive Firmware. Values of 00h indicates module supports only a single image.
85-117	33	Application Advertising	Combinations of host and media interfaces that are supported by module data path(s)
118-125	8	Password Entry and Change	
126	1	Bank Select Byte	Bank address of currently visible Page
127	1	Page Select Byte	Page address of currently visible Page

### Figure 6. The Lower Memory Overview



### The Upper Memory – Page 00h

Address	Size (bytes)	Name	Description
128	1	Identifier	Identifier Type of module
129-144	16	Vendor name	Vendor name (ASCII)
145-147	3	Vendor OUI	Vendor IEEE company ID
148-163	16	Vendor PN	Part number provided by vendor (ASCII)
164-165	2	Vendor rev	Revision level for part number provided by vendor (ASCII)
166-181	16	Vendor SN	Vendor Serial Number (ASCII)
182-189	8	Date Code	Contraction of the second s
190-199	10	CLEI code	Common Language Equipment Identification code
200-201	2	Module power characteristics	
202	1	Cable assembly length	
203	1	Media Connector Type	
204-209	6	Copper Cable Attenuation	
210-211	2	Cable Assembly Lane Information	
212	1	Media Interface Technology	
213-220	8	Reserved	
221	1	Custom	
222	1	Checksum	Includes bytes 128-221
223-255	33	Custom Info NV	

Upper page 00h contains static read-only module identification information.

### Figure 7. Page 00h Memory Overview

#### The Upper Memory – Page 01h (Advertising)

Upper page 01h contains advertising fields that define properties that are unique to active modules and cable assemblies.

Byte	Size (bytes)	Name	Description
128-131	4	Module Firmware and Hardware revisions	
132-137	6	Supported link length	Supported lengths of various fiber media
138-139	2	Nominal Wavelength	
140-141	2	Wavelength Tolerance	
142-144	3	Implemented Memory Pages and Durations advertising	
145-154	10	Module Characteristics advertising	
155-156	2	Implemented Controls advertising	
157-158	2	Implemented Flags advertising	
159-160	2	Implemented Monitors advertising	
161-162	2	Implemented Signal Integrity Controls advertising	
163-166	4	CDB support advertising	
167-168	2	Additional Durations advertising	
169-175	7	Reserved	
176-190	15	Module Media Lane advertising	2
191-222	32	Custom	
223-250	28	Extended Module Host-Media Interface Advertising options	
251-254	4	Reserved	
255	1	Checksum	Checksum of bytes 130-254 <sup>1</sup>

### Figure 8. Page 01h Memory Overview



### The Upper Memory – Page 02h (Module and Lane Thresholds)

Upper Page 02h contains the module-defined thresholds for module-level and lane-specific monitors. The presence of Page 02h is advertised in bit 7 in Page 00h byte 2.

Byte	Size (bytes)	Name	Description	
128-175	48	Module-level monitor thresholds		
176-199	24	Lane-specific monitor thresholds		
200-229	30	Reserved		
230-254	25	Custom		
255	1	Checksum	Covers bytes 128-254	

Figure 9. Page 02h Memory Overview

#### The Upper Memory – Page 10h (Lane and Data Path Control)

The upper memory map page 10h is a banked page that contains lane dynamic control bytes. The presence of Page 10h is advertised in bit 7 in Page 00h byte 2.

Byte	Size (bytes)	Name	Description
128	1	DataPathDeinit	Data Pathcontrol bits for each lane, controls Data Path State machine
129-142	14	Lane-Specific Control	Fields to control lane attributes independent of the Data Path State machine or control sets
143-177	35	Staged Control Set 0	Fields to configure the selected Application Code and signal integrity settings
178-212	35	Staged Control Set 1	Fields to configure the selected Application Code and signal integrity settings
213-231	19	Lane-Specific Flag Masks	
232-239	8	Reserved	
240-255	16	Custom	

Figure 10. Page 02h Memory Overview

### The Upper Memory – Page 11h (Lane Status)

The upper memory map page 11h is a banked page that contains lane dynamic status bytes. The presence of Page 11h is conditional on the state of bit 7 in Page 00h byte 2. All fields on Page 11h are read-only.

Byte Size Name (bytes)		Name	Description	
128-131	4	Data Path State indicators		
132-133	2	Reserved		
134-152	19	Lane-specific flags		
153	1	Reserved		
154-201	48	Lane-specific monitors		
202-205	4	Configuration Error Codes	Indicates validity of select Application codes	
206-234	29	Active Control Set		
235-239	5	Reserved		
240-255 16 Host Electrical to Module Media Lane Mapping			Indicates the mapping of Host Electrical lanes to Module Media lanes	

### Figure 11. Page 11h Memory Overview



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## Pin Descriptions (SFP56 end)

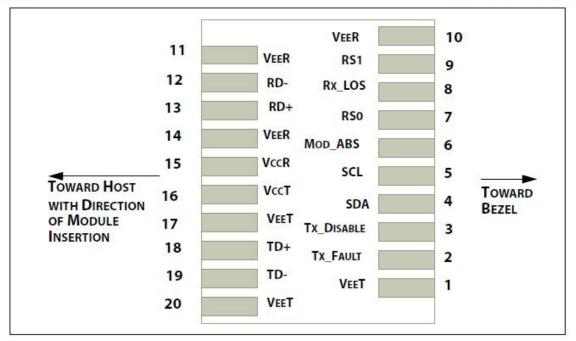
PIN	Logic	Symbol	Name / Description	Note
1		VeeT	Module Transmitter Ground	1
2	LVTTL-O	TX_Fault	Module Transmitter Fault	2
3	LVTTL-I	TX_Dis	Transmitter Disable; Turns off transmitter laser output	
4	LVTTL-I/O	SDA	2-Wire Serial Interface Data Line	2
5	LVTTL-I	SCL	2-Wire Serial Interface Clock	2
6		MOD_ABS	Module Definition, Grounded in the module	
7	LVTTL-I	RS0	Receiver Rate Select	
8	LVTTL-O	RX_LOS	Receiver Loss of Signal Indication Active LOW	
9	LVTTL-I	RS1	Transmitter Rate Select (not used)	
10		VeeR	Module Receiver Ground	1
11		VeeR	Module Receiver Ground	1
12	CML-O	RD-	Receiver Inverted Data Output	
13	CML-O	RD+	Receiver Data Output	
14		VeeR	Module Receiver Ground	1
15		VccR	Module Receiver 3.3 V Supply	
16		VccT	Module Receiver 3.3 V Supply	
17		VeeT	Module Transmitter Ground	1
18	CML-I	TD+	Transmitter Non-Inverted Data Input	
19	CML-I	TD-	Transmitter Inverted Data Input	
20		VeeT	Module Transmitter Ground	1

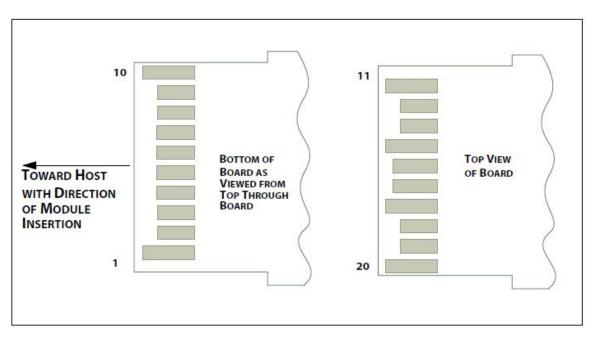
#### Notes:

1. Module ground pins GND are isolated from the module case.

Shall be pulled up with 4.7K-10Kohms to a voltage between 3.15V and 3.45V on the host board.

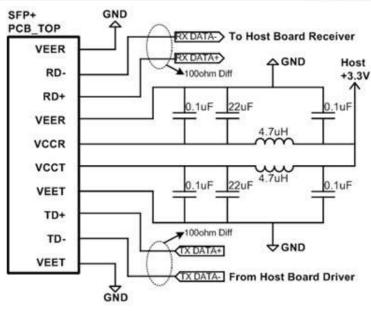


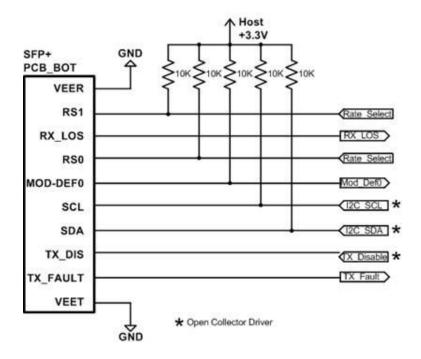




**Recommended Interface Circuit** 







**Mechanical Dimensions** 



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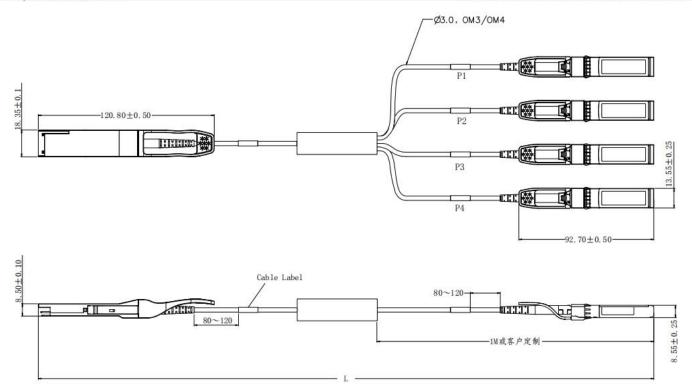


Figure 12. Mechanical Specifications

## **Regulatory Compliance**

Gigalight 50GBASE-SR200GbE to 4\*SFP56 AOC transceiver is Class 1 Laser Products.

They are certified per the following standards:

Feature	Agency	Standard
Laser Eye Safety	FDA/CDRH	CDRH 21 CFR 1040 and Laser Notice 50
EMC	FCC	47 CFR FCC Part 15 Subpart B
EMC CE-EMC		EN 55032:2015 EN 55024:2010+A1:2015 EN 61000-3-2:2014 EN 61000-3-3:2013

Complies with FDA performance standards for laser products except for deviations pursuant to Laser Notice No. 50, dated June 24, 2007.

### References

- 1. QSFP-MAS Rev3.0
- 2. IEEE802.3cd 200GBASE-SR4.



- 3. IEEE802.3cd 50GBASE-SR.
- 4. CMIS V4.0 Management Interface.

# **CAUTION:**

Use of controls or adjustment or performance of procedures other than those specified herein may result in hazardous radiation exposure.

### **Ordering Information**

Part Number	Product Description		
GQP-MDO201-XXXC	QSFP56, 200GbE to 4x53G SFP56 AOC MMF Active Optical Splitter Cable.		
XXX	005-5m, 020-20m, 050-50m, 100-100m		

### **Important Notice**

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### **Revision History**

Revision	Date	Description
V0	Jul-15-2021	Advance Release.